Re	eg No	D.: Name:	
		APJ ABDUL KALAM TECHNOLOGICAL UNIVERSITY EIGHTH SEMESTER B.TECH DEGREE EXAMINATION(S), OCTOBER 2019	
		Course Code: EC402 Course Name: NANOELECTRONICS	
Μ	ax. I	Marks: 100 Duration: 3	Hours
		PART A	
		Answer any two full questions, each carries 15 marks.	Marks
1	a)	Explain sol-gel process and how you can fabricate a quantum wire using the	(10)
		technique.	
	b)	Explain quantum mechanical coherence.	(5)
2	a)	Starting from Schrodinger equation, show that the density of states in a 2D nano material is independent of energy.	(10)
	b)	Explain the precipitation of quantum dots.	(5)
3	a)	Explain the different types of PVD techniques.	(10)
	b)	Explain any ten properties of graphene.	(5)
		PART B	
		Answer any two full questions, each carries 15 marks.	
4	a)	Define the term Photoluminescence. Discuss with neat diagrams PL spectroscopy	(10)
		in detail.	
	b)	Compare electron and optical microscope.	(5)
5	a)	Illustrate the working of SEM .Explain the different specimen interactions.	(10)
	b)	Explain how conductivity is increased in 2D electron gas in AlGaAs-GaAs	(5)
		structure.	
6	a)	Compare MQW with superlattice structure.	(8)
	b)	Explain modulation doping and why mobility of carrier increases in modulation	(7)
		doped structure.	
		PART C	
7	a)	Answer any two full questions, each carries 20 marks. Derive Landauer Formula and explain its significance.	(9)
	b)	Explain Landau levels and its variation with magnetic field.	(6)

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c) Explain perpendicular transport in quantum structure. (5)

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8	a)	Explain the Shubnikov-de Hass effect of magnetic fields on the electronic and	(10)		
		transport properties of the 2D systems.			
	b)	Explain Resonant Tunnel Effect and the operation of Resonant Tunnel Diodes.	(10)		
9	a)	Illustrate the working of a quantum well optical modulator.	(8)		
	b)	With the help of a neat schematic diagram explain MODFETs.	(8)		
	c)	Explain the concept of hot electrons.	(4)		

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